

SDM3400AV

30V N-Channel MOSFETs

Rev A.0

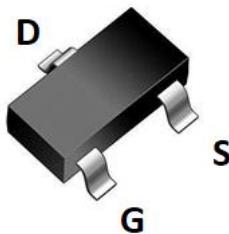
Feature

- ✧ Excellent $R_{DS(ON)}$
- ✧ Low Gate Charge
- ✧ Advanced Trench Technology
- ✧ Green product (RoHS compliant), lead free

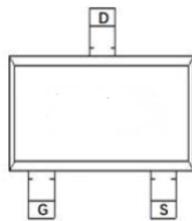
Product Summary

V_{DS}	30	V
$V_{GS(th)}_{Typ}$	0.95	V
$R_{DS(ON)}_{Typ}$ (at $V_{GS} = 10V$)	20.5	$m\Omega$
I_D (at $V_{GS} = 10V$)	5.8	A

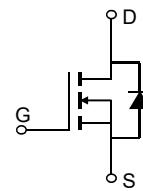
Type	Package	Marking	Outline	Media	Quantity (pcs)
SDM3400AV	SOT-23-3L	3400	Tape	7" Reel	3000



SOT-23 top view



Pin Assignment



Schematic Diagram

Absolute Maximum Ratings (Rating at $T_A=25^\circ C$ unless otherwise noted)

Parameter	Symbol	Maximum	Unit
Drain-Source Voltage	V_{DS}	30	V
Gate-Source Voltage	V_{GS}	± 12	V
Continuous Drain Current $T_A=25^\circ C$	I_D	5.8	A
$T_A=100^\circ C$		4	
Pulsed Drain Current ⁽¹⁾	I_{DM}	23	A
Maximum Body-Diode Continuous Current	I_S	5.8	A
Power Dissipation $T_A=25^\circ C$	P_D	1.3	W
Junction and Storage Temperature Range	T_J, T_{STG}	-55 to +150	$^\circ C$

SDM3400AV



Electrical Characteristics (Rating at $T_J=25^\circ\text{C}$ unless otherwise noted)

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
STATIC PARAMETERS						
BV_{DSS}	Drain-Source Breakdown Voltage	$I_D=250\mu\text{A}, V_{GS}=0\text{V}$	30	-	-	V
I_{DSS}	Zero Gate Voltage Drain Current	$V_{DS}=0\text{V}, V_{GS}=0\text{V}$	-	-	1	μA
I_{GSS}	Gate-Body Leakage Current	$V_{DS}=0\text{V}, V_{GS}=\pm 12\text{V}$	-	-	± 100	nA
$V_{GS(\text{th})}$	Gate Threshold Voltage	$V_{DS}=V_{GS}, I_D=250\mu\text{A}$	0.6	0.95	1.3	V
$R_{DS(\text{ON})}$	Static Drain-Source On-Resistance ⁽³⁾	$V_{GS}=10\text{V}, I_D=4.2\text{A}$	-	20.5	26.7	$\text{m}\Omega$
		$V_{GS}=4.5\text{V}, I_D=4\text{A}$	-	22	28.6	
		$V_{GS}=2.5\text{V}, I_D=1\text{A}$	-	27.1	35.2	
V_{SD}	Diode Forward Voltage	$I_S=2\text{A}, V_{GS}=0\text{V}$	-	-	1.2	V
DYNAMIC PARAMETERS						
C_{iss}	Input Capacitance	$V_{GS}=0\text{V}, V_{DS}=15\text{V}, f=1\text{MHz}$	-	783	-	pF
C_{oss}	Output Capacitance		-	67	-	pF
C_{rss}	Reverse Transfer Capacitance		-	53	-	pF
SWITCHING PARAMETERS						
Q_g	Total Gate Charge	$V_{GS}=0\sim 10\text{V} V_{DS}=15\text{V}, I_D=3\text{A}$	-	21	-	nC
Q_{gs}	Gate Source Charge		-	2.1	-	nC
Q_{gd}	Gate Drain Charge		-	2.3	-	nC
$t_{D(on)}$	Turn-On Delay Time	$V_{GS}=10\text{V}, V_{DD}=15\text{V}, R_G=3.0\Omega, I_D=3\text{A}$	-	4.1	-	ns
t_r	Turn-On Rise Time		-	13	-	ns
$t_{D(off)}$	Turn-Off Delay Time		-	25	-	ns
t_f	Turn-Off Fall Time		-	2.1	-	ns
t_{rr}	Body Diode Reverse Recovery Time	$I_f=3\text{A}, di/dt=100\text{A}/\mu\text{s}$	-	8.5	-	ns
Q_{rr}	Body Diode Reverse Recovery Charge	$I_f=3\text{A}, di/dt=100\text{A}/\mu\text{s}$	-	3.3	-	nC

Thermal Resistances

Symbol	Parameter	Typ	Max	Unit
R _{θJA}	Thermal resistance from junction to ambient ⁽²⁾	-	93	°C /W

Notes:

1. Repetitive Rating: Pulse Width Limited by Maximum Junction Temperature.
2. R_{θJA} is measured with the device mounted on a 1inch² pad of 2oz copper FR4 PCB
3. Pulse Test: Pulse Width≤300μs, Duty Cycle≤0.5%.

Typical Electrical and Thermal Characteristics

Figure 1: Saturation Characteristics

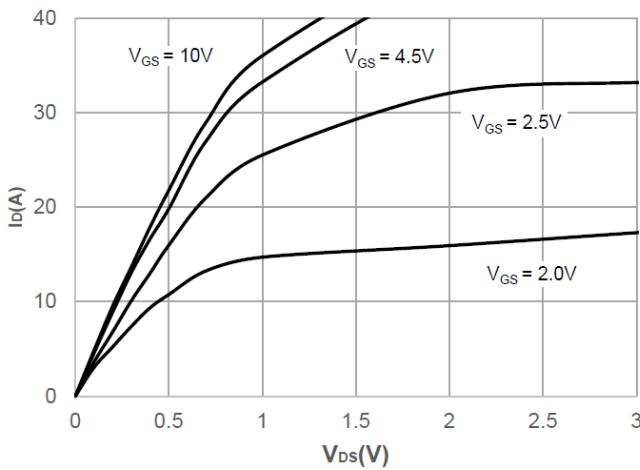


Figure 2: Transfer Characteristics

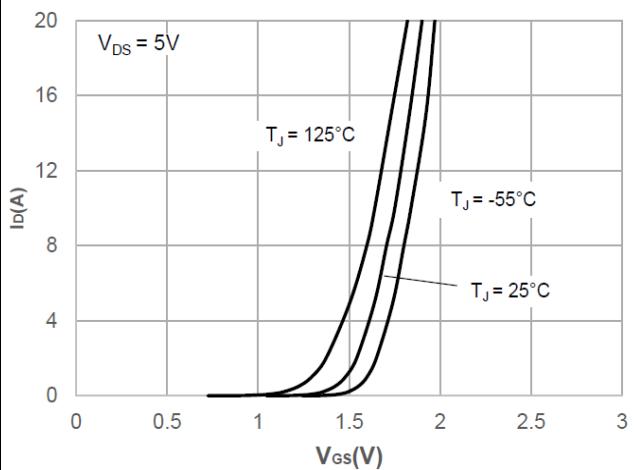
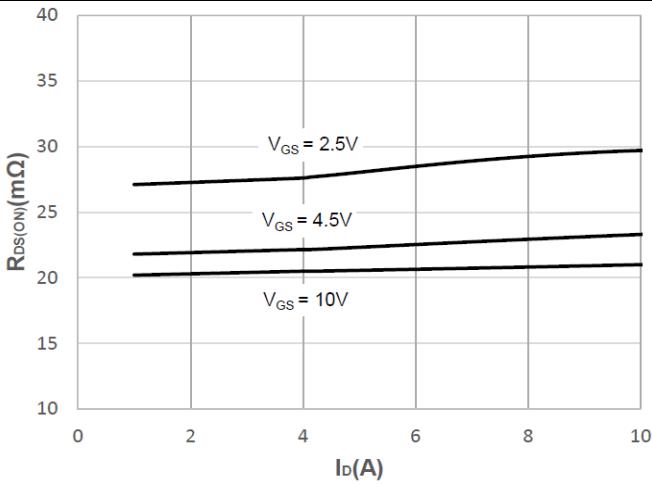
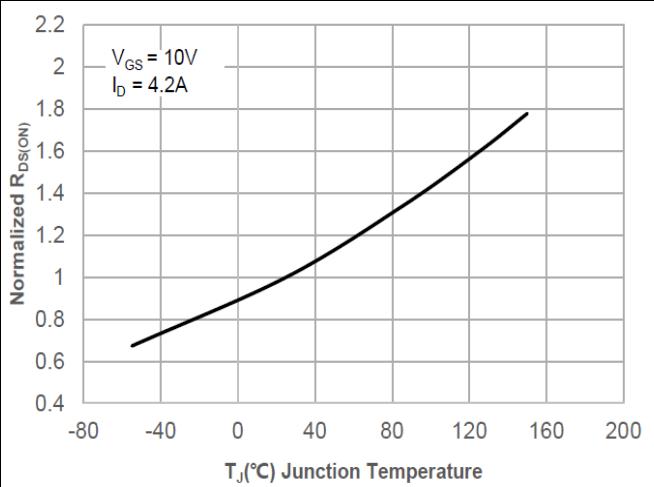
Figure 3: $R_{DS(ON)}$ vs. Drain CurrentFigure 4: $R_{DS(ON)}$ vs. Junction Temperature

Figure 5: Normalized Breakdown voltage vs. Junction Temperature

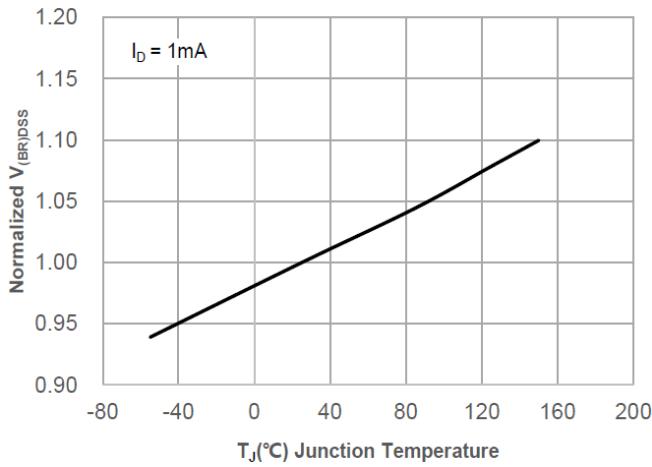
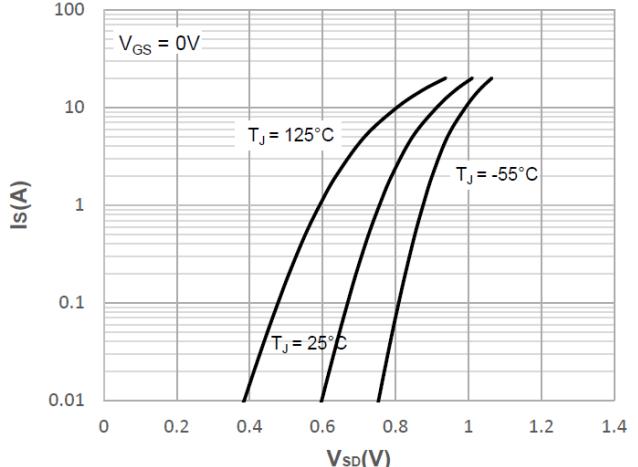


Figure 6: Body-Diode Characteristics



Typical Electrical and Thermal Characteristics

Figure 7: Gate-Charge characteristics

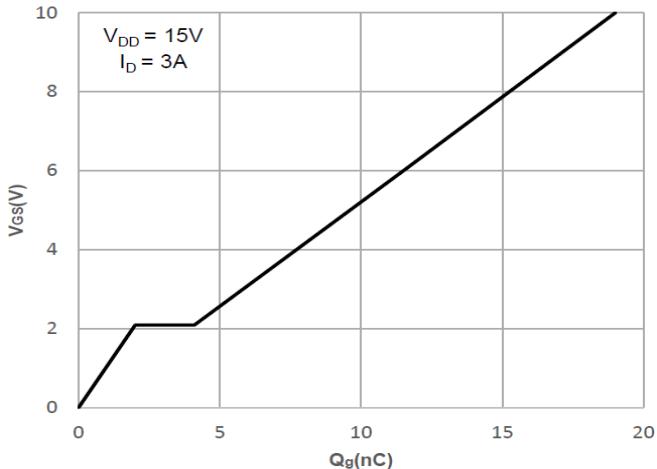


Figure 8: Capacitance characteristics

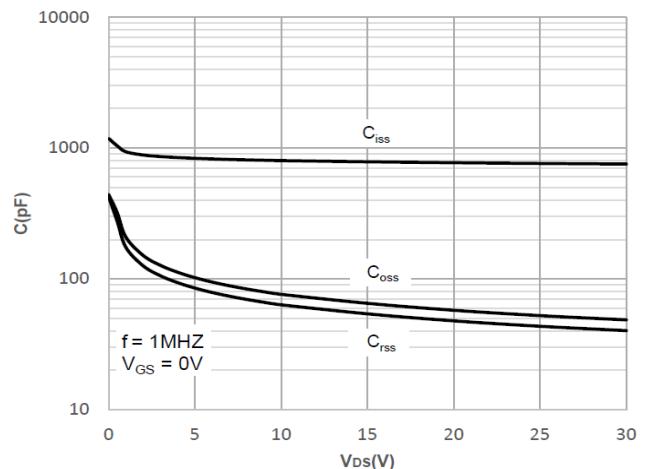


Figure 9: Current De-rating

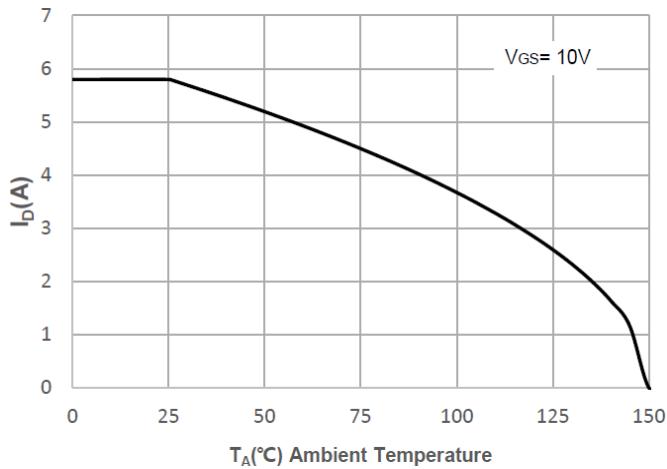


Figure 10: Peak Current Capacity

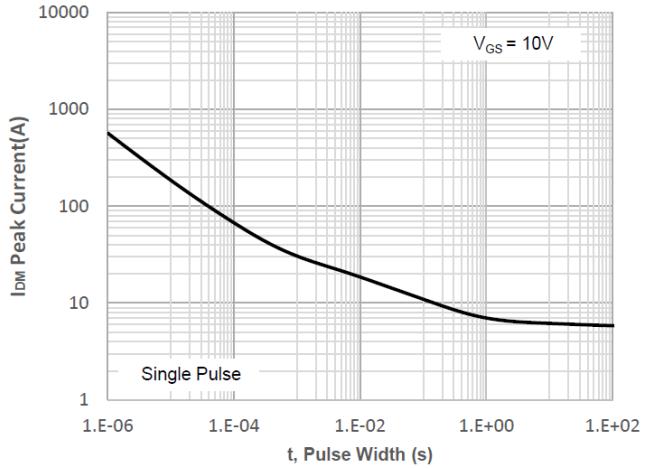


Figure 11: Maximum Safe Operating Area

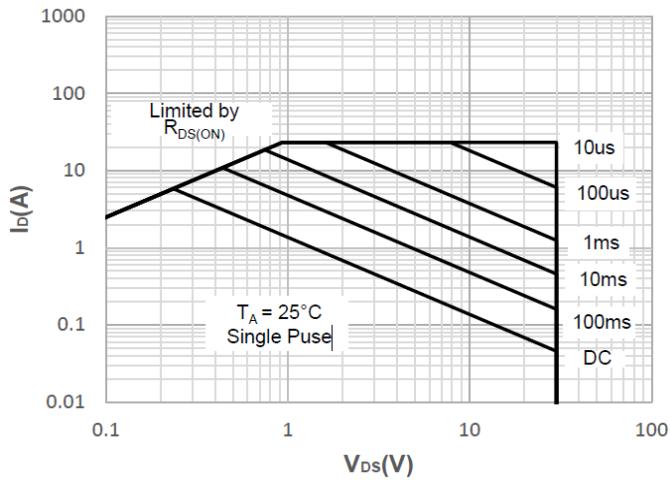
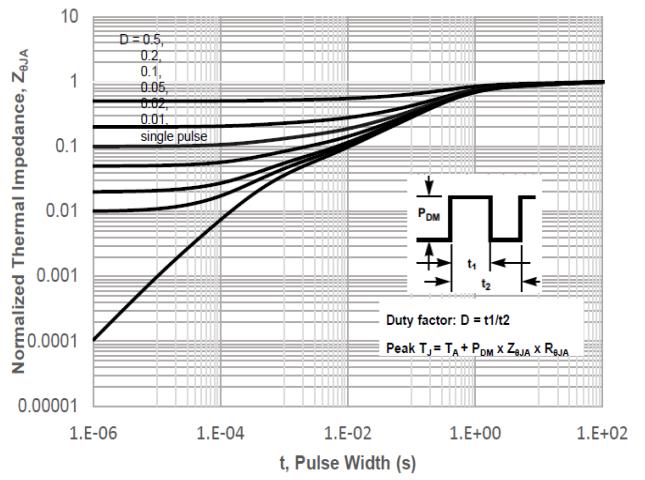


Figure 12: Normalized Maximum Transient Thermal Impedance



Test Circuit

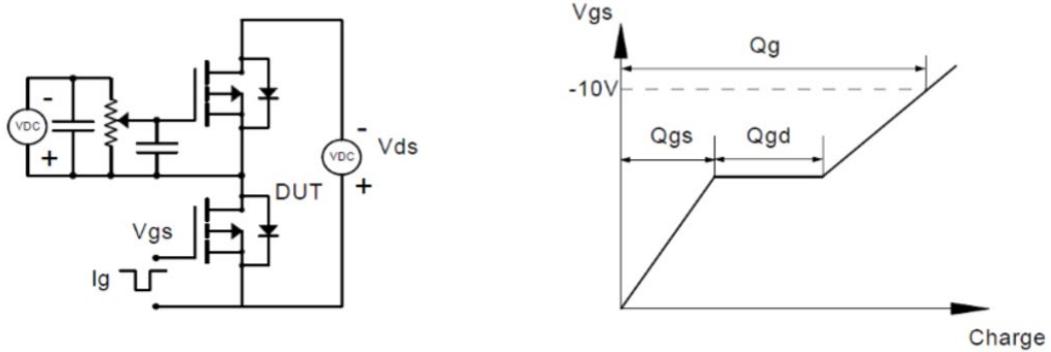


Figure1: Gate Charge Test Circuit & Waveforms

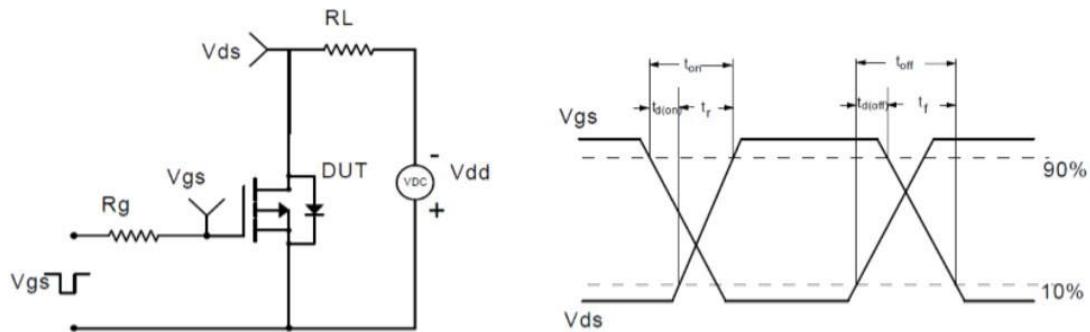


Figure2: Resistive Switching Test Circuit & Waveforms

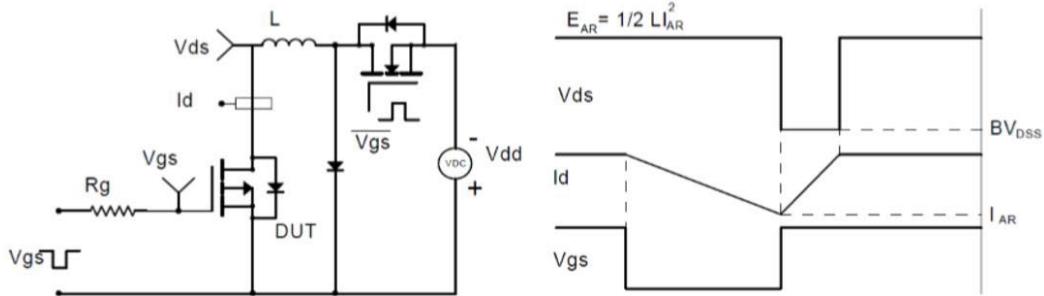


Figure3: Unclamped Inductive Switching (UIS) Test Circuit & Waveforms

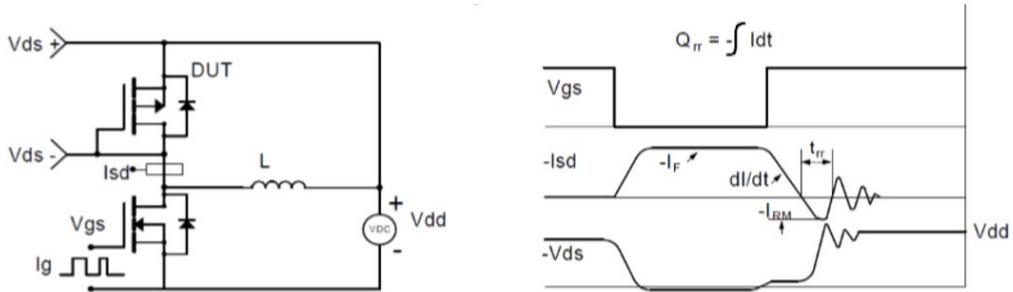
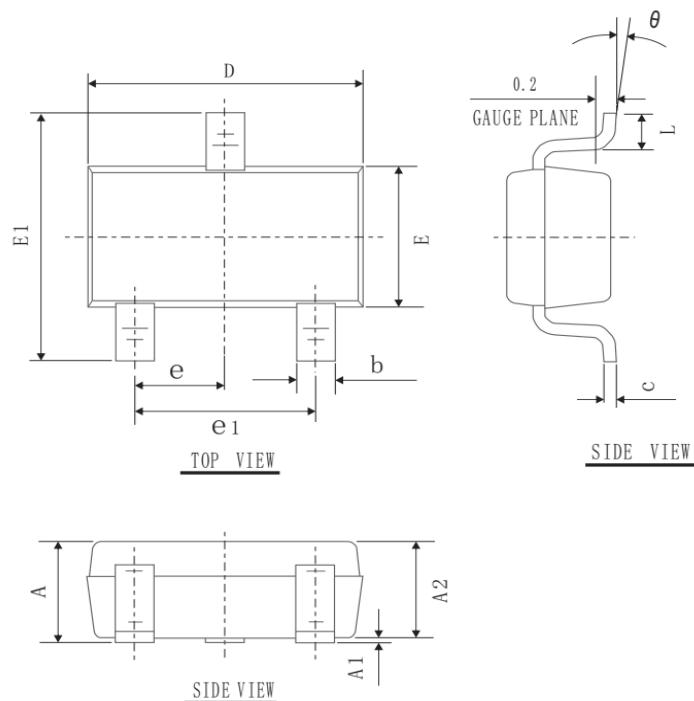


Figure4: Diode Recovery Test Circuit & Waveforms

SOT-23-3L Package Information



COMMON DIMENSIONS
(UNITS OF MEASURE=mm)

SYMBOL	MIN	NOM	MAX
A	—	—	1.30
A1	0.00	0.05	0.10
A2	1.00	1.10	1.20
b	0.30	0.40	0.50
c	0.119	0.127	0.135
e1	1.80	1.90	2.00
D	2.80	2.90	3.00
E	1.50	1.60	1.70
E1	2.60	2.80	3.00
L	0.30	0.45	0.60
θ	0°	4°	8°
e	0.95BSC		